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Embedded - System On Chip (SoC): The Heart of Modern Embedded Systems

Embedded - System On Chip (SoC) refers to an integrated circuit that consolidates all the essential components of a computer system into a single chip. This includes a microprocessor, memory, and other peripherals, all packed into one compact and efficient package. SoCs are designed to provide a complete computing solution, optimizing both space and power consumption, making them ideal for a wide range of embedded applications.

What are Embedded - System On Chip (SoC)?

System On Chip (SoC) integrates multiple functions of a computer or electronic system onto a single chip. Unlike traditional multi-chip solutions, SoCs combine a central

Details

| | |
|-------------------------|---|
| Product Status | Active |
| Architecture | MCU, FPGA |
| Core Processor | ARM® Cortex®-M3 |
| Flash Size | 128KB |
| RAM Size | 64KB |
| Peripherals | DDR |
| Connectivity | CANbus, Ethernet, I ² C, SPI, UART/USART, USB |
| Speed | 166MHz |
| Primary Attributes | FPGA - 5K Logic Modules |
| Operating Temperature | -40°C ~ 100°C (TJ) |
| Package / Case | 484-BGA |
| Supplier Device Package | 484-FPBGA (23x23) |
| Purchase URL | https://www.e-xfl.com/product-detail/microchip-technology/m2s005s-1fgg484i |

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1 Revision History

The revision history describes the changes that were implemented in the document. The changes are listed by revision, starting with the most current publication.

1.1 Revision 11.0

The following is a summary of the changes in revision 11.0 of this document.

- Updated [Table 24](#), page 22 with minimum and maximum values for input current low and high (SAR 73114 and 80314).
- Added [Non-Deterministic Random Bit Generator \(NRBG\) Characteristics](#), page 106 (SAR 73114 and 79517).
- Added 060 device in [Table 282](#), page 110 (SAR 79860).
- Added [DEVRST_N to Functional Times](#), page 116 (SAR 73114).
- Added [Cryptographic Block Characteristics](#), page 106 (SAR 73114 and 79516).
- Update [Table 296](#), page 121 with VTX-AMP details (SAR 81756).
- Update note in [Table 297](#), page 122 (SAR 74570 and 80677).
- Update [Table 298](#), page 122 with generic EPCS details (SAR 75307).
- Added [Table 308](#), page 129 (SAR 50424).

1.2 Revision 10.0

The following is a summary of the changes in revision 10.0 of this document.

- The Surge Current on VDD during DEVRST_B Assertion and Surge Current on VDD during Digest Check using System Services tables were deleted and added reference to [AC393: Board Design Guidelines for SmartFusion2 SoC and IGLOO2 FPGAs Application Note](#). (SAR 76865 and 76623).
- Added 060 device in [Table 4](#), page 6 (SAR 76383).
- Updated [Table 24](#), page 22 for ramp time input (SAR 72103).
- Added 060 device details in [Table 284](#), page 112 (SAR 74927).
- Updated [Table 290](#), page 116 for name change (SAR 74925).
- Updated [Table 283](#), page 111 for 060 FG676 Package details (SAR 78849).
- Updated [Table 305](#), page 126 for SmartFusion2 and [Table 310](#), page 129 for IGLOO2 for SPI timing and Fmax (SAR 56645, 75331).
- Updated [Table 293](#), page 119 for Flash*Freeze entry and exit times (SAR 75329, 75330).
- Updated [Table 297](#), page 122 for RX-CID information (SAR 78271).
- Added [Table 8](#), page 8 and [Figure 1](#), page 9 (SAR 78932).
- Updated [Table 223](#), page 76 for timing characteristics and [Table 224](#), page 77 (SAR 75998).
- Added [SRAM PUF](#), page 105 (SAR 64406).
- Added a footnote on digest cycle in [Table 5](#), page 7 (SAR 79812).

1.3 Revision 9.0

The following is a summary of the changes in revision 9.0 of this document.

- Added a note in [Table 5](#), page 7 (SAR 71506).
- Added a note in [Table 6](#), page 8 (SAR 74616).
- Added a note in [Figure 3](#), page 17 (SAR 71506).
- Updated Quiescent Supply Current for 060 in [Table 11](#), page 12 and [Table 12](#), page 13 (SAR 74483).
- Updated programming currents for 060 in [Table 13](#), page 13, [Table 14](#), page 13, and [Table 15](#), page 14.
- Added DEVRST_B assertion tables (SAR 74708).
- Updated I/O speeds for LVDS 3.3 V in [Table 18](#), page 19 and [Table 21](#), page 20 (SAR 69829).
- Updated [Table 24](#), page 22 (SAR 69418).
- Updated [Table 25](#), page 22, [Table 26](#), page 23, [Table 27](#), page 23 (SAR 74570).
- Updated all AC/DC table to link to the [Input Capacitance, Leakage Current, and Ramp Time](#), page 22 for reference (SAR 69418).

2.3.2 Power Consumption

The following sections describe the power consumptions of the devices.

2.3.2.1 Quiescent Supply Current

Table 10 • Quiescent Supply Current Characteristics

| Power Supplies/Blocks | Modes and Configurations | |
|---|--------------------------|--------------|
| | Non-Flash*Freeze | Flash*Freeze |
| FPGA Core | On | Off |
| V _{DD} /SERDES_[01]_VDD ¹ | On | On |
| V _{PP} /V _{PPNVM} | On | On |
| HPMS_MDDR_PLL_VDDA/FDDR_PLL_VDDA/ CCC_XX[01]_PLL_VDDA/PLL0_PLL1_HPMS_MDDR_VDD A | 0 V | 0 V |
| SERDES_[01]_PLL_VDDA ² | 0 V | 0 V |
| SERDES_[01]_L[0123]_VDDAPLL/VDD_2V5 ² | On | On |
| SERDES_[01]_L[0123]_VDDAIIO ² | On | On |
| V _{DDIx} ^{3, 4} | On | On |
| V _{REFx} | On | On |
| MSSDDR CLK | 32 kHz | 32 kHz |
| RAM | On | Sleep state |
| System controller | 50 MHz | 50 MHz |
| 50 MHz oscillator (enable/disable) | Enable | Disabled |
| 1 MHz oscillator (enable/disable) | Disabled | Disabled |
| Crystal oscillator (enable/disable) | Disabled | Disabled |

1. SERDES_[01]_VDD Power Supply is shorted to V_{DD}.
2. SerDes and DDR blocks to be unused.
3. V_{DDIx} has been set to ON for test conditions as described. Banks on the east side should always be powered with the appropriate V_{DDI} bank supplies. For details on bank power supplies, see "Recommendation for Unused Bank Supplies" table in the *AC393: SmartFusion2 and IGLOO2 Board Design Guidelines Application Note*.
4. No Differential (that is to say, LVDS) I/Os or ODT attributes to be used.

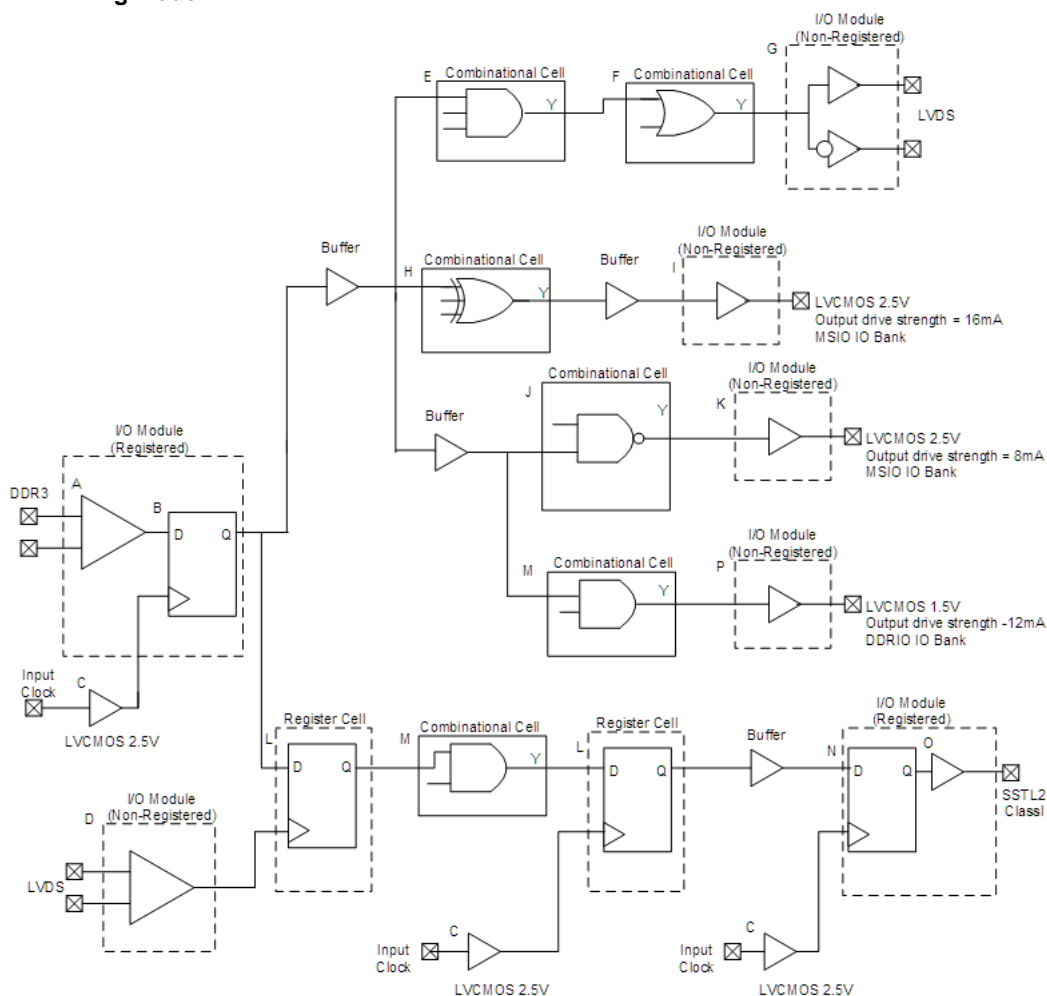
Table 11 • SmartFusion2 and IGLOO2 Quiescent Supply Current (V_{DD} = 1.2 V) – Typical Process

| Symbol | Modes | 005 | 010 | 025 | 050 | 060 | 090 | 150 | Unit | Conditions |
|--------|------------------|------|------|------|-------|-------|-------|-------|------|--------------------------------------|
| IDC1 | Non-Flash*Freeze | 6.2 | 6.9 | 8.9 | 13.1 | 15.3 | 15.4 | 27.5 | mA | Typical (T _J = 25 °C) |
| | | 24.0 | 28.4 | 40.6 | 67.8 | 80.6 | 81.4 | 144.7 | mA | Commercial (T _J = 85 °C) |
| | | 35.2 | 41.9 | 60.5 | 102.1 | 121.4 | 122.6 | 219.1 | mA | Industrial (T _J = 100 °C) |

2.3.4 Timing Model

This section describes timing model and timing parameters.

Figure 2 • Timing Model



The following table lists the timing model parameters in worst commercial-case conditions when $T_J = 85^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

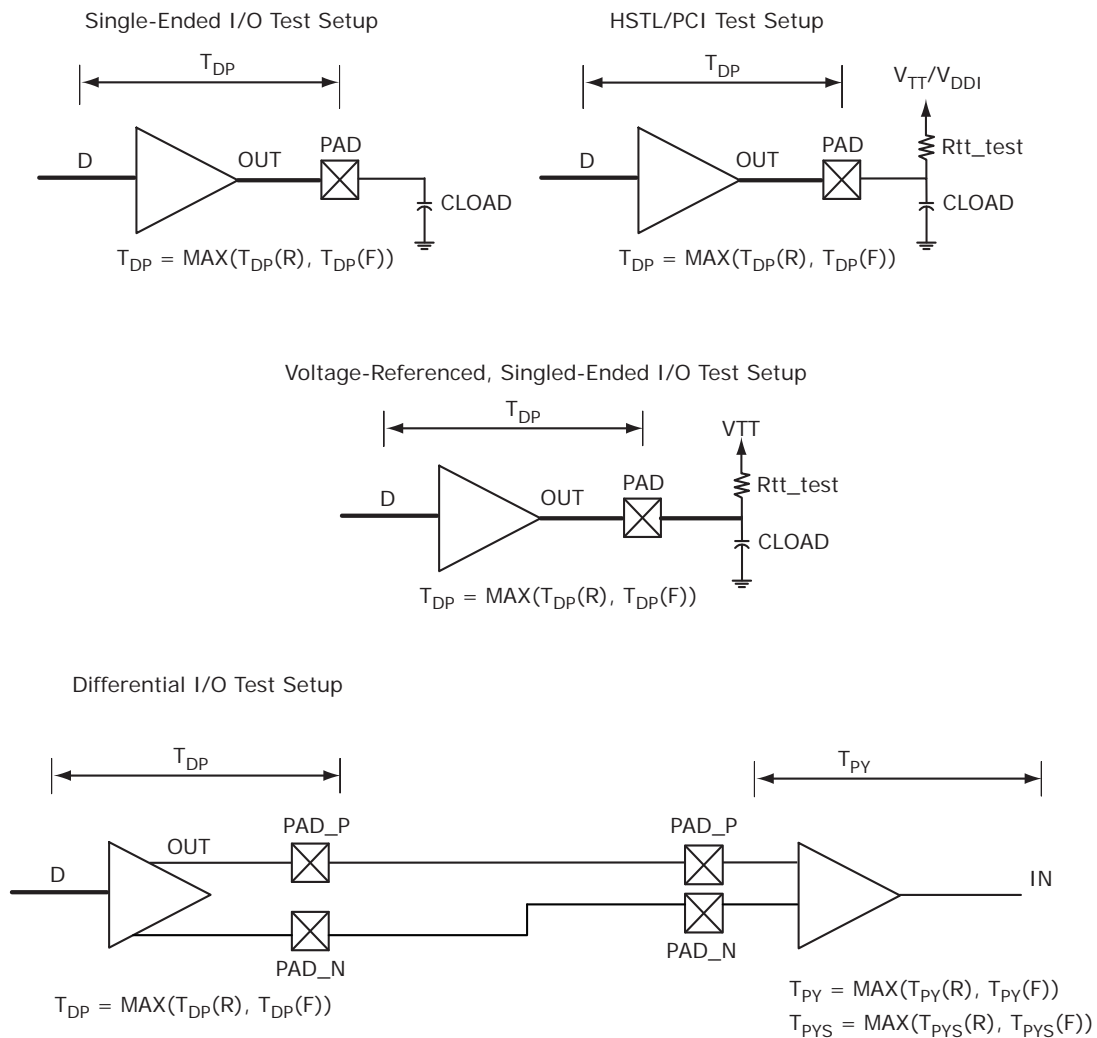
Table 17 • Timing Model Parameters

| Index | Symbol | Description | -1 | Unit | For More Information |
|-------|-------------|---|-------|------|------------------------|
| A | T_{PY} | Propagation delay of DDR3 receiver | 1.605 | ns | See Table 137, page 50 |
| B | T_{ICLKQ} | Clock-to-Q of the input data register | 0.16 | ns | See Table 221, page 71 |
| | T_{ISUD} | Setup time of the input data register | 0.357 | ns | See Table 221, page 71 |
| C | T_{RCKH} | Input high delay for global clock | 1.53 | ns | See Table 227, page 78 |
| | T_{RCKL} | Input low delay for global clock | 0.897 | ns | See Table 227, page 78 |
| D | T_{PY} | Input propagation delay of LVDS receiver | 2.774 | ns | See Table 167, page 56 |
| E | T_{DP} | Propagation delay of a three-input AND gate | 0.198 | ns | See Table 223, page 76 |

2.3.5.2 Output Buffer and AC Loading

The following figure shows the output buffer and AC loading.

Figure 4 • Output Buffer AC Loading



The following table lists the minimum and maximum I/O weak pull-up/pull-down resistance values of MSIO I/O bank at V_{OH}/V_{OL} Level.

Table 26 • I/O Weak Pull-Up/Pull-Down Resistances for MSIO I/O Bank

| V_{DDI} Domain | R(WEAK PULL-UP) at V_{OH} (Ω) | | R(WEAK PULL-DOWN) at V_{OL} (Ω) | |
|-----------------------|--|-------|--|-------|
| | Min | Max | Min | Max |
| 3.3 V | 9.9K | 17.1K | 9.98K | 17.5K |
| 2.5 V ^{1, 2} | 10K | 17.6K | 10.1K | 18.4K |
| 1.8 V ^{1, 2} | 10.4K | 19.1K | 10.4K | 20.4K |
| 1.5 V ^{1, 2} | 10.7K | 20.4K | 10.8K | 22.2K |
| 1.2 V ^{1, 2} | 11.3K | 23.2K | 11.5K | 26.7K |

1. $R(\text{WEAK PULL-DOWN}) = (V_{OL\text{spec}})/I(\text{WEAK PULL-DOWN MAX})$.
2. $R(\text{WEAK PULL-UP}) = (V_{DDI\text{max}} - V_{OH\text{spec}})/I(\text{WEAK PULL-UP MIN})$.

The following table lists the minimum and maximum I/O weak pull-up/pull-down resistance values of MSIOD I/O bank at V_{OH}/V_{OL} Level.

Table 27 • I/O Weak Pull-up/Pull-down Resistances for MSIOD I/O Bank

| V_{DDI} Domain | R(WEAK PULL-UP) at V_{OH} (Ω) | | R(WEAK PULL-DOWN) at V_{OL} (Ω) | |
|-----------------------|--|-------|--|-------|
| | Min | Max | Min | Max |
| 2.5 V ^{1, 2} | 9.6K | 16.6K | 9.5K | 16.4K |
| 1.8 V ^{1, 2} | 9.7K | 17.3K | 9.7K | 17.1K |
| 1.5 V ^{1, 2} | 9.9K | 18K | 9.8K | 17.6K |
| 1.2 V ^{1, 2} | 10.3K | 19.6K | 10K | 19.1K |

1. $R(\text{WEAK PULL-DOWN}) = (V_{OL\text{spec}})/I(\text{WEAK PULL-DOWN MAX})$.
2. $R(\text{WEAK PULL-UP}) = (V_{DDI\text{max}} - V_{OH\text{spec}})/I(\text{WEAK PULL-UP MIN})$.

The following table lists the hysteresis voltage value for schmitt trigger mode input buffers.

Table 28 • Schmitt Trigger Input Hysteresis

| Input Buffer Configuration | Hysteresis Value (Typical, unless otherwise noted) |
|-----------------------------------|--|
| 3.3 V LVTTTL/LVCMOS/ PCI/PCI-X | $0.05 \times V_{DDI}$ (worst-case) |
| 2.5 V LVCMOS | $0.05 \times V_{DDI}$ (worst-case) |
| 1.8 V LVCMOS | $0.1 \times V_{DDI}$ (worst-case) |
| 1.5 V LVCMOS | 60 mV |
| 1.2 V LVCMOS | 20 mV |

2.3.5.7 2.5 V LVCMOS

LVCMOS 2.5 V is a general standard for 2.5 V applications and is supported in IGLOO2 FPGA and SmartFusion2 SoC FPGAs that are in compliance with the JEDEC specification JESD8-5A.

Minimum and Maximum DC/AC Input and Output Levels Specification

Table 38 • LVCMOS 2.5 V DC Recommended DC Operating Conditions

| Parameter | Symbol | Min | Typ | Max | Unit |
|----------------|-----------|-------|-----|-------|------|
| Supply voltage | V_{DDI} | 2.375 | 2.5 | 2.625 | V |

Table 39 • LVCMOS 2.5 V DC Input Voltage Specification

| Parameter | Symbol | Min | Max | Unit |
|---|---------------|------|-------|------|
| DC input logic high (for MSIOD and DDRIO I/O banks) | V_{IH} (DC) | 1.7 | 2.625 | V |
| DC input logic high (for MSIO I/O bank) | V_{IH} (DC) | 1.7 | 3.45 | V |
| DC input logic low | V_{IL} (DC) | -0.3 | 0.7 | V |
| Input current high ¹ | I_{IH} (DC) | | | |
| Input current low ¹ | I_{IL} (DC) | | | |

1. See [Table 24](#), page 22.

Table 40 • LVCMOS 2.5 V DC Output Voltage Specification

| Parameter | Symbol | Min | Max | Unit |
|----------------------|-----------------------|-----------------|-----|------|
| DC output logic high | V_{OH} ¹ | $V_{DDI} - 0.4$ | - | V |
| DC output logic low | V_{OL} ² | | 0.4 | V |

1. The VOH/VOL test points selected ensure compliance with LVCMOS 2.5 V JEDEC8-5A requirements.

Table 41 • LVCMOS 2.5 V AC Minimum and Maximum Switching Speed

| Parameter | Symbol | Max | Unit | Conditions |
|--|-----------|-----|------|--|
| Maximum data rate (for DDRIO I/O bank) | D_{MAX} | 400 | Mbps | AC loading: 17 pF load, maximum drive/slew |
| Maximum data rate (for MSIO I/O bank) | D_{MAX} | 410 | Mbps | AC loading: 17 pF load, maximum drive/slew |
| Maximum data rate (for MSIOD I/O bank) | D_{MAX} | 420 | Mbps | AC loading: 17 pF load, maximum drive/slew |

Table 42 • LVCMOS 2.5 V AC Calibrated Impedance Option

| Parameter | Symbol | Typ | Unit |
|---|----------|------------------------|----------|
| Supported output driver calibrated impedance (for DDRIO I/O bank) | Rodt_cal | 75, 60, 50, 33, 25, 20 | Ω |

Table 136 • SSTL15 AC Test Parameter Specifications (for DDRIO I/O Bank Only)

| Parameter | Symbol | Typ | Unit |
|--|----------------|------|----------|
| Measuring/trip point for data path | V_{TRIP} | 0.75 | V |
| Resistance for enable path (T_{ZH} , T_{ZL} , T_{HZ} , T_{LZ}) | R_{ENT} | 2K | Ω |
| Capacitive loading for enable path (T_{ZH} , T_{ZL} , T_{HZ} , T_{LZ}) | C_{ENT} | 5 | pF |
| Reference resistance for data test path for SSTL15 Class I (T_{DP}) | R_{TT_TEST} | 50 | Ω |
| Reference resistance for data test path for SSTL15 Class II (T_{DP}) | R_{TT_TEST} | 25 | Ω |
| Capacitive loading for data path (T_{DP}) | C_{LOAD} | 5 | pF |

AC Switching Characteristics

Worst commercial-case conditions: $T_J = 85\text{ }^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$, $V_{DDI} = 1.425\text{ V}$

Table 137 • DDR3/SSTL15 Receiver Characteristics for DDRIO I/O Bank – with Calibration Only

| | On-Die Termination (ODT) | T_{PY} | | Unit |
|---------------------|--------------------------|----------|-------|------|
| | | -1 | -Std | |
| Pseudo differential | None | 1.605 | 1.888 | ns |
| | 20 | 1.616 | 1.901 | ns |
| | 30 | 1.613 | 1.897 | ns |
| | 40 | 1.611 | 1.895 | ns |
| | 60 | 1.609 | 1.893 | ns |
| | 120 | 1.607 | 1.89 | ns |
| True differential | None | 1.623 | 1.91 | ns |
| | 20 | 1.637 | 1.926 | ns |
| | 30 | 1.63 | 1.918 | ns |
| | 40 | 1.626 | 1.914 | ns |
| | 60 | 1.622 | 1.91 | ns |
| | 120 | 1.619 | 1.905 | ns |

Table 138 • DDR3/SSTL15 Transmitter Characteristics (Output and Tristate Buffers)

| | T_{DP} | | T_{ZL} | | T_{ZH} | | T_{HZ} | | T_{LZ} | | Unit |
|---|----------|-------|----------|-------|----------|-------|----------|-------|----------|-------|------|
| | -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | |
| DDR3 Reduced Drive/SSTL15 Class I (for DDRIO I/O Bank) | | | | | | | | | | | |
| Single-ended | 2.533 | 2.98 | 2.522 | 2.967 | 2.523 | 2.968 | 2.427 | 2.855 | 2.428 | 2.856 | ns |
| Differential | 2.555 | 3.005 | 3.073 | 3.615 | 3.073 | 3.615 | 2.416 | 2.843 | 2.416 | 2.843 | ns |
| DDR3 Full Drive/SSTL15 Class II (for DDRIO I/O Bank) | | | | | | | | | | | |
| Single-ended | 2.53 | 2.977 | 2.514 | 2.958 | 2.516 | 2.96 | 2.422 | 2.849 | 2.425 | 2.852 | ns |
| Differential | 2.552 | 3.002 | 2.591 | 3.048 | 2.59 | 3.047 | 2.882 | 3.391 | 2.881 | 3.39 | ns |

AC Switching Characteristics

Worst commercial-case conditions: $T_J = 85\text{ }^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$, $V_{DDI} = 2.375\text{ V}$.

Table 210 • RSDS AC Switching Characteristics for Receiver (for MSIO I/O Bank - Input Buffers)

| On-Die Termination (ODT) | T_{PY} | | Unit |
|--------------------------|----------|-------|------|
| | -1 | -Std | |
| None | 2.855 | 3.359 | ns |
| 100 | 2.85 | 3.353 | ns |

Table 211 • RSDS AC Switching Characteristics for Receiver (for MSIOD I/O Bank - Input Buffers)

| On-Die Termination (ODT) | T_{PY} | | Unit |
|--------------------------|----------|-------|------|
| | -1 | -Std | |
| None | 2.602 | 3.061 | ns |
| 100 | 2.597 | 3.055 | ns |

Table 212 • RSDS AC Switching Characteristics for Transmitter (for MSIO I/O Bank - Output and Tristate Buffers)

| T_{DP} | | T_{ZL} | | T_{ZH} | | T_{HZ} | | T_{LZ} | | Unit |
|----------|-------|----------|-------|----------|-------|----------|-------|----------|------|------|
| -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | |
| 2.097 | 2.467 | 2.303 | 2.709 | 2.291 | 2.695 | 1.961 | 2.307 | 1.947 | 2.29 | ns |

Table 213 • RSDS AC Switching Characteristics for Transmitter (for MSIOD I/O Bank - Output and Tristate Buffers)

| | T_{DP} | | T_{ZL} | | T_{ZH} | | T_{HZ} | | T_{LZ} | | Unit |
|------------------|----------|-------|----------|-------|----------|-------|----------|-------|----------|-------|------|
| | -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | |
| No pre-emphasis | 1.614 | 1.899 | 1.559 | 1.834 | 1.55 | 1.823 | 1.59 | 1.87 | 1.575 | 1.852 | ns |
| Min pre-emphasis | 1.604 | 1.887 | 1.742 | 2.05 | 1.728 | 2.032 | 1.889 | 2.222 | 1.858 | 2.185 | ns |
| Med pre-emphasis | 1.521 | 1.79 | 1.753 | 2.062 | 1.737 | 2.043 | 1.9 | 2.235 | 1.868 | 2.197 | ns |
| Max pre-emphasis | 1.492 | 1.754 | 1.762 | 2.073 | 1.745 | 2.052 | 1.91 | 2.247 | 1.876 | 2.206 | ns |

2.3.7.6 LVPECL

Low-Voltage Positive Emitter-Coupled Logic (LVPECL) is another differential I/O standard. It requires that one data bit be carried through two signal lines. Similar to LVDS, two pins are needed. It also requires external resistor termination. IGLOO2 and SmartFusion2 SoC FPGAs support only LVPECL receivers and do not support LVPECL transmitters.

Minimum and Maximum Input and Output Levels (Applicable to MSIO I/O Bank Only)

Table 214 • LVPECL Recommended DC Operating Conditions

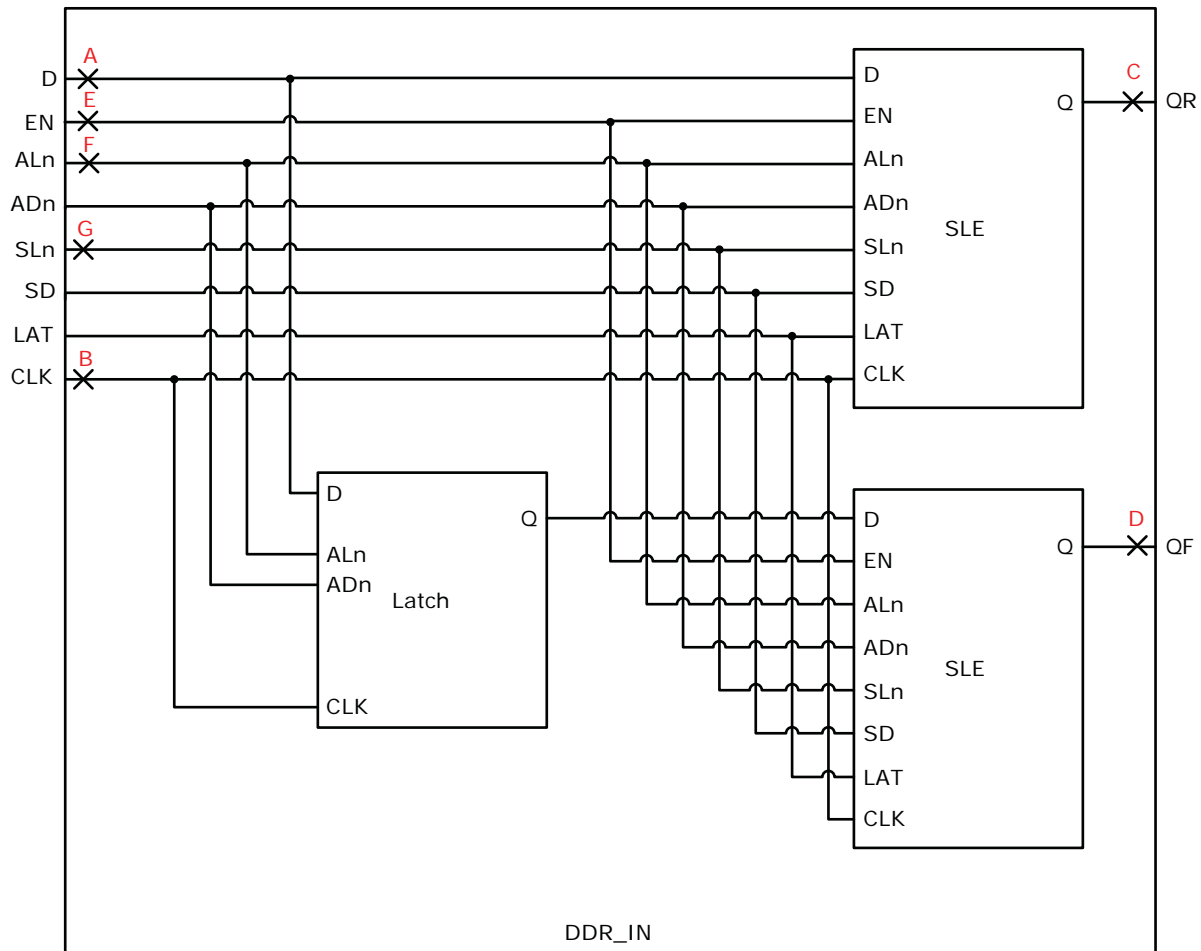
| Parameter | Symbol | Min | Typ | Max | Unit |
|----------------|-----------|------|-----|------|------|
| Supply voltage | V_{DDI} | 3.15 | 3.3 | 3.45 | V |

2.3.9 DDR Module Specification

This section describes input and output DDR module and timing specifications.

2.3.9.1 Input DDR Module

Figure 10 • Input DDR Module



2.3.9.4 Output DDR Module

Figure 12 • Output DDR Module

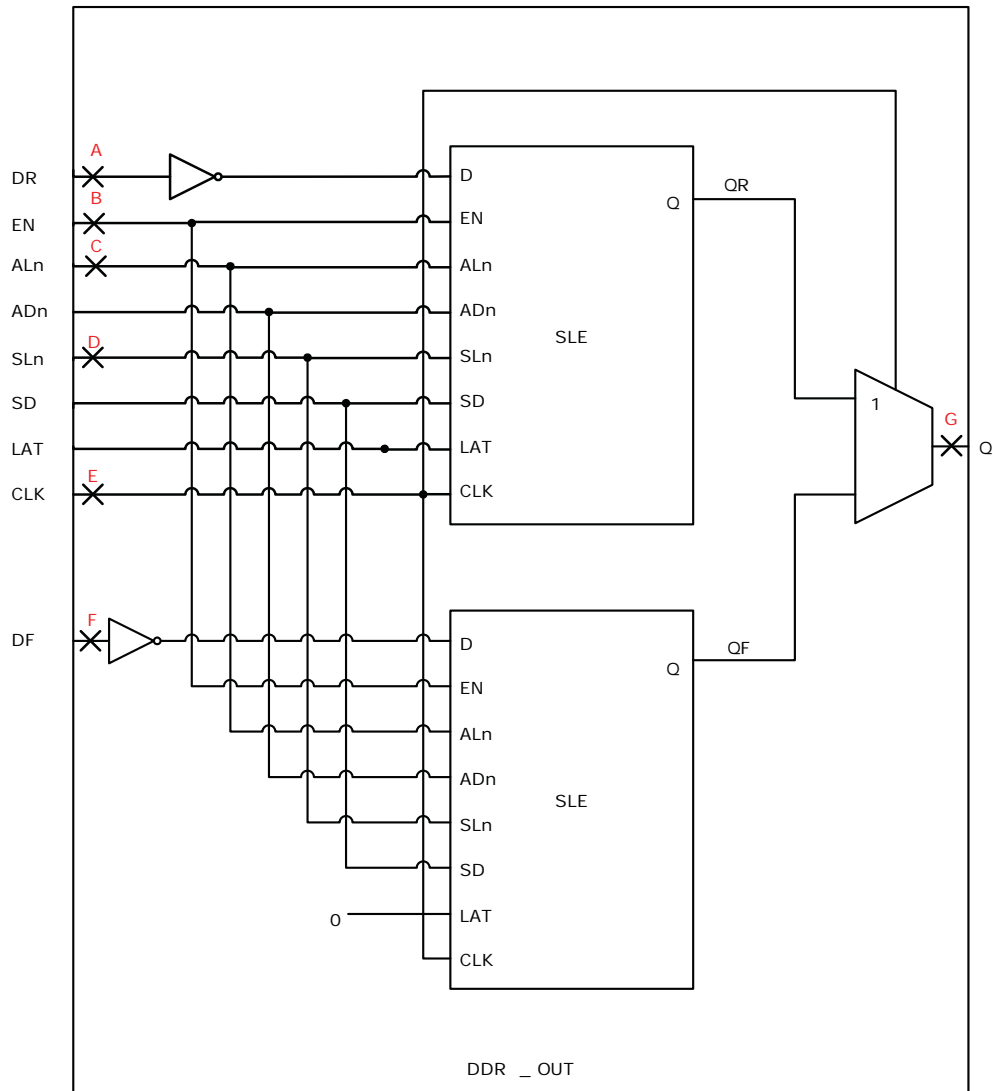
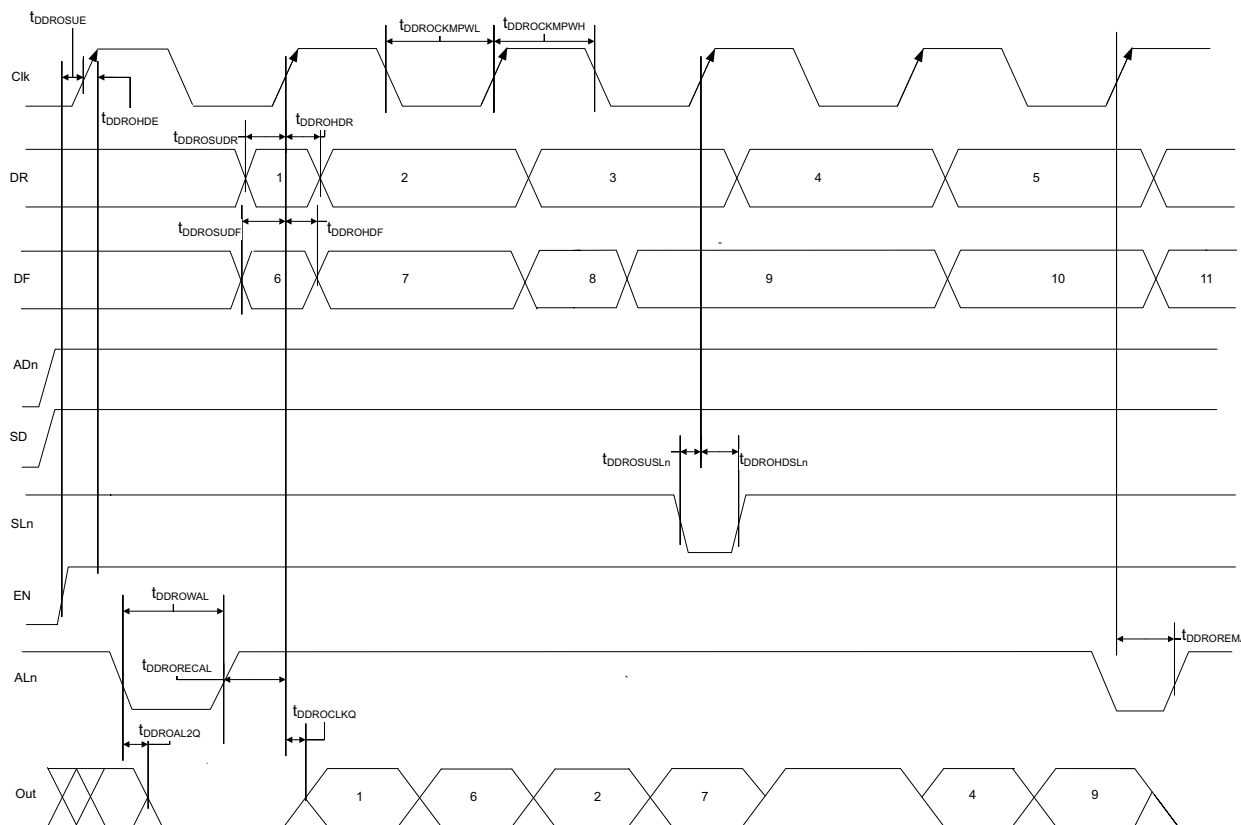


Figure 13 • Output DDR Timing Diagram



2.3.9.5 Timing Characteristics

The following table lists the output DDR propagation delays in worst commercial-case conditions when $T_J = 85^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 222 • Output DDR Propagation Delays

| Symbol | Description | Measuring Nodes (from, to) | -1 | -Std | Unit |
|-----------------|--|----------------------------|-------|-------|------|
| $T_{DDROCLKQ}$ | Clock-to-out of DDR for output DDR | E, G | 0.263 | 0.309 | ns |
| $T_{DDROSUDF}$ | Data_F data setup for output DDR | F, E | 0.143 | 0.168 | ns |
| $T_{DDROSUDR}$ | Data_R data setup for output DDR | A, E | 0.19 | 0.223 | ns |
| $T_{DDROHDF}$ | Data_F data hold for output DDR | F, E | 0 | 0 | ns |
| $T_{DDROHDR}$ | Data_R data hold for output DDR | A, E | 0 | 0 | ns |
| $T_{DDROSUE}$ | Enable setup for input DDR | B, E | 0.419 | 0.493 | ns |
| T_{DDROHE} | Enable hold for input DDR | B, E | 0 | 0 | ns |
| $T_{DDROSUSLn}$ | Synchronous load setup for input DDR | D, E | 0.196 | 0.231 | ns |
| $T_{DDROHSLn}$ | Synchronous load hold for input DDR | D, E | 0 | 0 | ns |
| $T_{DDROAL2Q}$ | Asynchronous load-to-out for output DDR | C, G | 0.528 | 0.621 | ns |
| $T_{DDROREMA}$ | Asynchronous load removal time for output DDR | C, E | 0 | 0 | ns |
| $T_{DDRORECAL}$ | Asynchronous load recovery time for output DDR | C, E | 0.034 | 0.04 | ns |

Table 233 • RAM1K18 – Dual-Port Mode for Depth x Width Configuration 4K x 4 (continued)

| Parameter | Symbol | –1 | | –Std | | Unit |
|--|-----------------|--------|-------|--------|-------|------|
| | | Min | Max | Min | Max | |
| Pipelined clock minimum pulse width low | $T_{PLCLKMPWL}$ | 1.125 | | 1.323 | | ns |
| Read access time with pipeline register | | | 0.323 | | 0.38 | ns |
| Read access time without pipeline register | T_{CLK2Q} | | 2.273 | | 2.673 | ns |
| Access time with feed-through write timing | | | 1.511 | | 1.778 | ns |
| Address setup time | T_{ADDRSU} | 0.543 | | 0.638 | | ns |
| Address hold time | T_{ADDRHD} | 0.274 | | 0.322 | | ns |
| Data setup time | T_{DSU} | 0.334 | | 0.393 | | ns |
| Data hold time | T_{DHD} | 0.082 | | 0.096 | | ns |
| Block select setup time | T_{BLKSU} | 0.207 | | 0.244 | | ns |
| Block select hold time | T_{BLKHD} | 0.216 | | 0.254 | | ns |
| Block select to out disable time (when pipelined register is disabled) | T_{BLK2Q} | | 1.511 | | 1.778 | ns |
| Block select minimum pulse width | T_{BLKMPW} | 0.186 | | 0.219 | | ns |
| Read enable setup time | T_{RDESU} | 0.516 | | 0.607 | | ns |
| Read enable hold time | T_{RDEHD} | 0.071 | | 0.083 | | ns |
| Pipelined read enable setup time (A_DOUT_EN, B_DOUT_EN) | $T_{RDPLESU}$ | 0.248 | | 0.291 | | ns |
| Pipelined read enable hold time (A_DOUT_EN, B_DOUT_EN) | $T_{RDPLEHD}$ | 0.102 | | 0.12 | | ns |
| Asynchronous reset to output propagation delay | T_{R2Q} | | 1.507 | | 1.773 | ns |
| Asynchronous reset removal time | T_{RSTREM} | 0.506 | | 0.595 | | ns |
| Asynchronous reset recovery time | T_{RSTREC} | 0.004 | | 0.005 | | ns |
| Asynchronous reset minimum pulse width | T_{RSTMPW} | 0.301 | | 0.354 | | ns |
| Pipelined register asynchronous reset removal time | $T_{PLRSTREM}$ | –0.279 | | –0.328 | | ns |
| Pipelined register asynchronous reset recovery time | $T_{PLRSTREC}$ | 0.327 | | 0.385 | | ns |
| Pipelined register asynchronous reset minimum pulse width | $T_{PLRSTMPW}$ | 0.282 | | 0.332 | | ns |
| Synchronous reset setup time | T_{SRSTSU} | 0.226 | | 0.265 | | ns |
| Synchronous reset hold time | T_{SRSTHD} | 0.036 | | 0.043 | | ns |
| Write enable setup time | T_{WESU} | 0.458 | | 0.539 | | ns |
| Write enable hold time | T_{WEHD} | 0.048 | | 0.057 | | ns |
| Maximum frequency | F_{MAX} | | 400 | | 340 | MHz |

Table 240 • μ SRAM (RAM128x8) in 128 x 8 Mode (continued)

| Parameter | Symbol | -1 | | -Std | | Unit |
|---|----------------|--------|-------|--------|-------|------|
| | | Min | Max | Min | Max | |
| Read address hold time in synchronous mode | T_{ADDRHD} | 0.091 | | 0.107 | | ns |
| Read address hold time in asynchronous mode | | -0.778 | | -0.915 | | ns |
| Read enable setup time | T_{RDENSU} | 0.278 | | 0.327 | | ns |
| Read enable hold time | T_{RDENHD} | 0.057 | | 0.067 | | ns |
| Read block select setup time | T_{BLKSU} | 1.839 | | 2.163 | | ns |
| Read block select hold time | T_{BLKHD} | -0.65 | | -0.765 | | ns |
| Read block select to out disable time (when pipelined register is disabled) | T_{BLK2Q} | | 2.036 | | 2.396 | ns |
| Read asynchronous reset removal time (pipelined clock) | T_{RSTREM} | -0.023 | | -0.027 | | ns |
| Read asynchronous reset removal time (non-pipelined clock) | | 0.046 | | 0.054 | | ns |
| Read asynchronous reset recovery time (pipelined clock) | T_{RSTREC} | 0.507 | | 0.597 | | ns |
| Read asynchronous reset recovery time (non-pipelined clock) | | 0.236 | | 0.278 | | ns |
| Read asynchronous reset to output propagation delay (with pipelined register enabled) | T_{R2Q} | | 0.835 | | 0.982 | ns |
| Read synchronous reset setup time | T_{SRSTSU} | 0.271 | | 0.319 | | ns |
| Read synchronous reset hold time | T_{SRSTHD} | 0.061 | | 0.071 | | ns |
| Write clock period | T_{CCY} | 4 | | 4 | | ns |
| Write clock minimum pulse width high | $T_{CCLKMPWH}$ | 1.8 | | 1.8 | | ns |
| Write clock minimum pulse width low | $T_{CCLKMPWL}$ | 1.8 | | 1.8 | | ns |
| Write block setup time | T_{BLKCSU} | 0.404 | | 0.476 | | ns |
| Write block hold time | T_{BLKCHD} | 0.007 | | 0.008 | | ns |
| Write input data setup time | T_{DINCSU} | 0.115 | | 0.135 | | ns |
| Write input data hold time | T_{DINCHD} | 0.15 | | 0.177 | | ns |
| Write address setup time | $T_{ADDRCSU}$ | 0.088 | | 0.104 | | ns |
| Write address hold time | $T_{ADDRCHD}$ | 0.128 | | 0.15 | | ns |
| Write enable setup time | T_{WECSU} | 0.397 | | 0.467 | | ns |
| Write enable hold time | T_{WECHD} | -0.026 | | -0.03 | | ns |
| Maximum frequency | F_{MAX} | | 250 | | 250 | MHz |

Table 241 • μ SRAM (RAM256x4) in 256 x 4 Mode (continued)

| Parameter | Symbol | -1 | | -Std | | Unit |
|-------------------------|---------------|-------|-----|-------|-----|------|
| | | Min | Max | Min | Max | |
| Write address hold time | $T_{ADDRCHD}$ | 0.245 | | 0.288 | | ns |
| Write enable setup time | T_{WECSU} | 0.397 | | 0.467 | | ns |
| Write enable hold time | T_{WECHD} | -0.03 | | -0.03 | | ns |
| Maximum frequency | F_{MAX} | | 250 | | 250 | MHz |

The following table lists the μ SRAM in 512 x 2 mode in worst commercial-case conditions when $T_J = 85^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 242 • μ SRAM (RAM512x2) in 512 x 2 Mode

| Parameter | Symbol | -1 | | -Std | | Unit |
|---|-----------------|-------|-------|-------|-------|------|
| | | Min | Max | Min | Max | |
| Read clock period | T_{CY} | 4 | | 4 | | ns |
| Read clock minimum pulse width high | $T_{CLKMPWH}$ | 1.8 | | 1.8 | | ns |
| Read clock minimum pulse width low | $T_{CLKMPWL}$ | 1.8 | | 1.8 | | ns |
| Read pipeline clock period | T_{PLCY} | 4 | | 4 | | ns |
| Read pipeline clock minimum pulse width high | $T_{PLCLKMPWH}$ | 1.8 | | 1.8 | | ns |
| Read pipeline clock minimum pulse width low | $T_{PLCLKMPWL}$ | 1.8 | | 1.8 | | ns |
| Read access time with pipeline register | T_{CLK2Q} | | 0.27 | | 0.31 | ns |
| Read access time without pipeline register | | | | 1.76 | | 2.08 |
| Read address setup time in synchronous mode | T_{ADDRSU} | 0.301 | | 0.354 | | ns |
| Read address setup time in asynchronous mode | | | 1.96 | | 2.306 | |
| Read address hold time in synchronous mode | T_{ADDRHD} | 0.137 | | 0.161 | | ns |
| Read address hold time in asynchronous mode | | | -0.58 | | -0.68 | |
| Read enable setup time | T_{RDENSU} | 0.278 | | 0.327 | | ns |
| Read enable hold time | T_{RDENHD} | 0.057 | | 0.067 | | ns |
| Read block select setup time | T_{BLKSU} | 1.839 | | 2.163 | | ns |
| Read block select hold time | T_{BLKHD} | -0.65 | | -0.77 | | ns |
| Read block select to out disable time (when pipelined register is disabled) | T_{BLK2Q} | | 2.14 | | 2.52 | ns |
| Read asynchronous reset removal time (pipelined clock) | T_{RSTREM} | -0.02 | | -0.03 | | ns |
| Read asynchronous reset removal time (non-pipelined clock) | | | 0.046 | | 0.054 | |
| Read asynchronous reset recovery time (pipelined clock) | T_{RSTREC} | 0.507 | | 0.597 | | ns |
| Read asynchronous reset recovery time (non-pipelined clock) | | | 0.236 | | 0.278 | |
| Read asynchronous reset to output propagation delay (with pipelined register enabled) | T_{R2Q} | | 0.83 | | 0.98 | ns |
| Read synchronous reset setup time | T_{SRSTSU} | 0.271 | | 0.319 | | ns |
| Read synchronous reset hold time | T_{SRSTHD} | 0.061 | | 0.071 | | ns |

2.3.22 JTAG

Table 284 • JTAG 1532 for 005, 010, 025, and 050 Devices

| Parameter | Symbol | 005 | | 010 | | 025 | | 050 | | Unit |
|-----------------------------|---------------|-------|-------|-------|-------|-------|-------|-------|-------|------|
| | | -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | |
| Clock to Q (data out) | T_{TCK2Q} | 7.47 | 8.79 | 7.73 | 9.09 | 7.75 | 9.12 | 7.89 | 9.28 | ns |
| Reset to Q (data out) | T_{RSTB2Q} | 7.65 | 9 | 6.43 | 7.56 | 6.13 | 7.21 | 7.40 | 8.70 | ns |
| Test data input setup time | T_{DISU} | -1.05 | -0.89 | -0.69 | -0.59 | -0.67 | -0.57 | -0.30 | -0.25 | ns |
| Test data input hold time | T_{DIHD} | 2.38 | 2.8 | 2.38 | 2.8 | 2.42 | 2.85 | 2.09 | 2.45 | ns |
| Test mode select setup time | T_{TMSSU} | -0.73 | -0.62 | -1.03 | -1.21 | -1.1 | -0.94 | 0.28 | 0.33 | ns |
| Test mode select hold time | T_{TMDHD} | 1.36 | 1.6 | 1.43 | 1.68 | 1.93 | 2.27 | 0.16 | 0.19 | ns |
| ResetB removal time | $T_{TRSTREM}$ | -0.77 | -0.65 | -1.08 | -0.92 | -1.33 | -1.13 | -0.45 | -0.38 | ns |
| ResetB recovery time | $T_{TRSTREC}$ | -0.76 | -0.65 | -1.07 | -0.91 | -1.34 | -1.14 | -0.45 | -0.38 | ns |
| TCK maximum frequency | F_{TCKMAX} | 25 | 21.25 | 25 | 21.25 | 25 | 21.25 | 25.00 | 21.25 | MHz |

Table 285 • JTAG 1532 for 060, 090, and 150 Devices

| Parameter | Symbol | 060 | | 090 | | 150 | | Unit |
|-----------------------------|---------------|-------|-------|-------|-------|-------|-------|------|
| | | -1 | -Std | -1 | -Std | -1 | -Std | |
| Clock to Q (data out) | T_{TCK2Q} | 8.38 | 9.86 | 8.96 | 10.54 | 8.66 | 10.19 | ns |
| Reset to Q (data out) | T_{RSTB2Q} | 8.54 | 10.04 | 7.75 | 9.12 | 8.79 | 10.34 | ns |
| Test data input setup time | T_{DISU} | -1.18 | -1 | -1.31 | -1.11 | -0.96 | -0.82 | ns |
| Test data input hold time | T_{DIHD} | 2.52 | 2.97 | 2.68 | 3.15 | 2.57 | 3.02 | ns |
| Test mode select setup time | T_{TMSSU} | -0.97 | -0.83 | -1.02 | -0.87 | -0.53 | -0.45 | ns |
| Test mode select hold time | T_{TMDHD} | 1.7 | 2 | 1.67 | 1.96 | 1.02 | 1.2 | ns |
| ResetB removal time | $T_{TRSTREM}$ | -1.21 | -1.03 | -0.76 | -0.65 | -1.03 | -0.88 | ns |
| ResetB recovery time | $T_{TRSTREC}$ | -1.21 | -1.03 | -0.77 | -0.65 | -1.03 | -0.88 | ns |
| TCK maximum frequency | F_{TCKMAX} | 25 | 21.25 | 25 | 21.25 | 25 | 21.25 | MHz |

2.3.23 System Controller SPI Characteristics

The following table lists the system controller characteristics in worst-case industrial conditions when $T_J = 100\text{ }^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 286 • System Controller SPI Characteristics for All Devices

| Symbol | Description | Conditions | Min | Typ | Unit |
|------------------|---|---|-----|-------|------|
| sp1 | SC_SPI_SCK minimum period | | 20 | | ns |
| sp2 | SC_SPI_SCK minimum pulse width high | | 10 | | ns |
| sp3 | SC_SPI_SCK minimum pulse width low | | 10 | | ns |
| sp4 ¹ | SC_SPI_SCK, SC_SPI_SDO, SC_SPI_SS rise time (10%–90%) 1 | I/O configuration: LVTTTL 3.3 V–20 mA AC loading: 35 pF Test conditions: Typical voltage, 25 °C | | 1.239 | ns |
| sp5 ¹ | SC_SPI_SCK, SC_SPI_SDO, SC_SPI_SS fall time (10%–90%) 1 | I/O configuration: LVTTTL 3.3 V–20 mA AC loading: 35 pF Test conditions: Typical voltage, 25 °C | | 1.245 | ns |
| sp6 | Data from master (SC_SPI_SDO) setup time | | 160 | | ns |
| sp7 | Data from master (SC_SPI_SDO) hold time | | 160 | | ns |
| sp8 | SC_SPI_SDI setup time | | 20 | | ns |
| sp9 | SC_SPI_SDI hold time | | 20 | | ns |

- For specific Rise/Fall Times, board design considerations and detailed output buffer resistances, use the corresponding IBIS models located on the Microsemi SoC Products Group website: <http://www.microsemi.com/soc/download/ibis/default.aspx>. Use the supported I/O Configurations for the System Controller SPI in the following table.

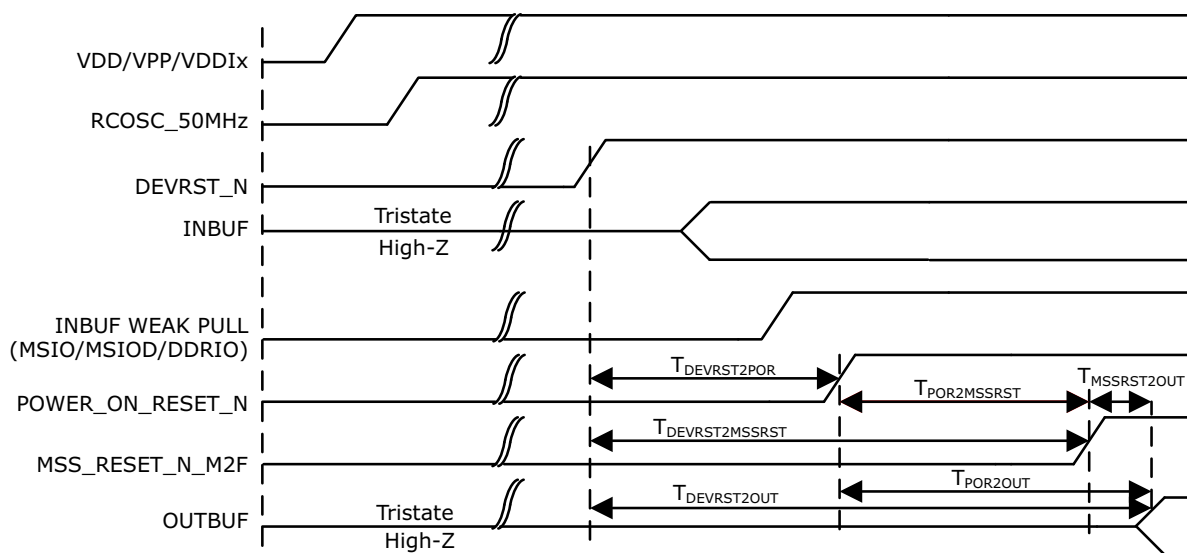
Table 287 • Supported I/O Configurations for System Controller SPI (for MSIO Bank Only)

| Voltage Supply | I/O Drive Configuration | Unit |
|----------------|-------------------------|------|
| 3.3 V | 20 | mA |
| 2.5 V | 16 | mA |
| 1.8 V | 12 | mA |
| 1.5 V | 8 | mA |
| 1.2 V | 4 | mA |

Table 291 • DEVRST_N to Functional Times for SmartFusion2 (continued)

| Symbol | From | To | Description | Maximum Power-up to Functional Time for SmartFusion2 (uS) | | | | | | |
|---------------------|----------|-----------------------|---|---|-----|-----|-----|-----|-----|-----|
| | | | | 005 | 010 | 025 | 050 | 060 | 090 | 150 |
| $T_{DEVRST2POR}$ | DEVRST_N | POWER_ON_RESET_N | V_{DD} at its minimum threshold level to fabric | 233 | 289 | 216 | 213 | 237 | 234 | 219 |
| $T_{DEVRST2MSSRST}$ | DEVRST_N | MSS_RESET_N_M2F | V_{DD} at its minimum threshold level to MSS | 702 | 765 | 712 | 688 | 636 | 630 | 866 |
| $T_{DEVRST2WPU}$ | DEVRST_N | DDRIO Inbuf weak pull | DEVRST_N to Inbuf weak pull | 208 | 202 | 197 | 193 | 216 | 215 | 215 |
| | DEVRST_N | MSIO Inbuf weak pull | DEVRST_N to Inbuf weak pull | 208 | 202 | 197 | 193 | 216 | 215 | 215 |
| | DEVRST_N | MSIOD Inbuf weak pull | DEVRST_N to Inbuf weak pull | 208 | 202 | 197 | 193 | 216 | 215 | 215 |

Figure 19 • DEVRST_N to Functional Timing Diagram for SmartFusion2



The following table lists the receiver pa in worst-case industrial conditions when $T_J = 100\text{ }^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 297 • Receiver Parameters

| Symbol | Description | Min | Typ | Max | Unit |
|----------------------|---|-------|-------|-------|---------------|
| VRX-IN-PP-CC | Differential input peak-to-peak sensitivity (2.5 Gbps) | 0.238 | | 1.2 | V |
| | Differential input peak-to-peak sensitivity (2.5 Gbps, de-emphasized) | 0.219 | | 1.2 | V |
| | Differential input peak-to-peak sensitivity (5.0 Gbps) | 0.300 | | 1.2 | V |
| | Differential input peak-to-peak sensitivity (5.0 Gbps, de-emphasized) | 0.300 | | 1.2 | V |
| VRX-CM-AC-P | Input common mode range (AC coupled) | | | 150 | mV |
| ZRX-DIFF-DC | Differential input termination | 80 | 100 | 120 | Ω |
| REXT | External calibration resistor | 1,188 | 1,200 | 1,212 | Ω |
| CDR-LOCK-RST | CDR relock time from reset | | | 15 | μs |
| RLRX-DIFF | Return loss differential mode (2.5 Gbps) | -10 | | | dB |
| | Return loss differential mode (5.0 Gbps) | | | | |
| | 0.05 GHz to 1.25 GHz | -10 | | | dB |
| | 1.25 GHz to 2.5 GHz | -8 | | | dB |
| RLRX-CM | Return loss common mode (2.5 Gbps, 5.0 Gbps) | -6 | | | dB |
| RX-CID ¹ | CID limit PCIe Gen1/2 | | | 200 | UI |
| VRX-IDLE-DET-DIFF-PP | Signal detect limit | 65 | | 175 | mV |

1. AC-coupled, BER = e^{-12} , using synchronous clock.

Table 298 • SerDes Protocol Compliance

| Protocol | Maximum Data Rate (Gbps) | -1 | -Std |
|--------------|--------------------------|-----|------|
| PCIe Gen 1 | 2.5 | Yes | Yes |
| PCIe Gen 2 | 5.0 | Yes | |
| XAUI | 3.125 | Yes | |
| Generic EPCS | 3.2 | Yes | |
| Generic EPCS | 2.5 | Yes | Yes |